INTEGRATED CIRCUITS

DATA SHEET



74LV244Octal buffer/line driver (3-State)

Product specification Supersedes data of 1997 Feb 19 IC24 Data Handbook





Octal buffer/line driver (3-State)

74LV244

FEATURES

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for low voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- \bullet Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V, T_{amb} = 25°C
- \bullet Typical V_{OHV} (output V_{OH} undershoot) > 2 V at V_{CC} = 3.3 V, T_{amb} = 25°C
- Output capability: bus driver
- I_{CC} category: MSI

DESCRIPTION

The 74LV244 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT244.

The 74LV244 is an octal non-inverting buffer/line driver with 3-State outputs. The 3-State outputs are controlled by the output enable inputs $1\overline{OE}$ and $2\overline{OE}$. A HIGH on $n\overline{OE}$ causes the outputs to assume a high impedance OFF-state. The 74LV244 is identical to the 74LV240 but has non-inverting outputs.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay 1A _n to 1Y _n ; 2A _n to 2Y _n	C _L = 15 pF; V _{CC} = 3.3 V	8.0	ns
C _I	Input capacitance	20 3	3.5	pF
C _{PD}	Power dissipation capacitance per buffer	$V_{CC} = 3.3 \text{ V}$ $V_{I} = \text{GND to V}_{CC}^{1}$	35	pF

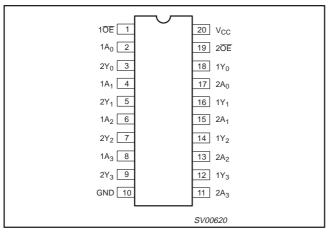
NOTE:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW) $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; C_L = output load capacitance in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V; $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

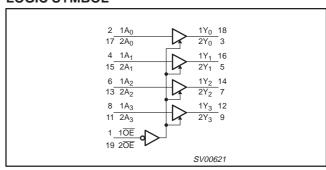
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic DIL	-40°C to +125°C	74LV244 N	74LV244 N	SOT146-1
20-Pin Plastic SO	-40°C to +125°C	74LV244 D	74LV244 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +125°C	74LV244 DB	74LV244 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV244 PW	74LV244PW DH	SOT360-1

PIN CONFIGURATION



LOGIC SYMBOL



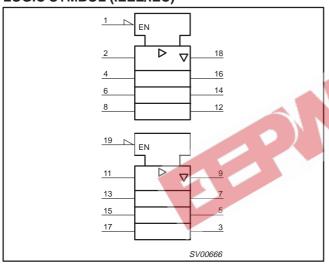
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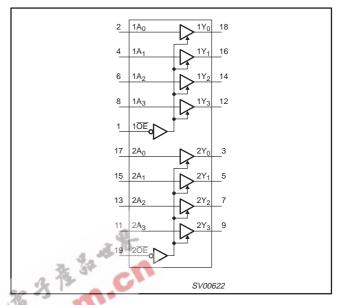
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1 1 OE		Output enable input (active LOW)
2, 4, 6, 8	1A ₀ to 1A ₃	Data inputs
3, 5, 7, 9	2Y ₀ to 2Y ₃	Bus outputs
10	GND	Ground (0 V)
17, 15, 13, 11	2A ₀ to 2A ₃	Data inputs
18, 16, 14, 12	1Y ₀ to 1Y ₃	Bus outputs
19	2 OE	Output enable input (active LOW)
20	V _{CC}	Positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



FUNCTION TABLE

INP	INPUTS							
nOE	nA _n	nY _n						
L	L	L						
L	Н	Н						
Н	Х	Z						

NOTES:

H = HIGH voltage level L = LOW voltage level

X = don't care

Z = high impedance OFF-state

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
V _I	Input voltage		0	_	V _{CC}	V
V _O	Output voltage		0	_	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$ $V_{CC} = 3.6V \text{ to } 5.5V$	- - -	- - - -	500 200 100 50	ns/V

NOTE:

ABSOLUTE MAXIMUM RATINGS^{1, 2}

n accordance	E MAXIMUM RATINGS^{1, 2} with the Absolute Maximum Rating System (IEC referenced to GND (ground = 0V).	134).		
SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage	4 32	-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_{I} < -0.5$ or $V_{I} > V_{GC} + 0.5V$	20	mA
± I _{OK}	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5V$	50	mA
± I _O	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
± I _{GND} , ± I _{CC}	DC V _{CC} or GND current for types with – bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

The LV is guaranteed to function down to $V_{CC} = 1.0V$ (input levels GND or V_{CC}); DC characteristics are guaranteed from $V_{CC} = 1.2V$ to

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40	°C to +8	5°C	-40°C to	+125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	
		V _{CC} = 1.2V	0.9			0.9		
V_{IH}	HIGH level Input	V _{CC} = 2.0V	1.4			1.4		
VIН	voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	2.0			2.0		ľ
		$V_{CC} = 4.5 \text{ to } 5.5 \text{V}$	0.7 * V _{CC}			0.7 * V _{CC}		
		V _{CC} = 1.2V			0.3		0.3]
V_{IL}	LOW level Input	V _{CC} = 2.0V			0.6		0.6	_V
۷IL	voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$			0.8		0.8	ľ
		$V_{CC} = 4.5 \text{ to } 5.5$			0.3 * V _{CC}		0.3 * V _{CC}	
		$V_{CC} = 1.2V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$		1.2				
		$V_{CC} = 2.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	1.8	2.0	5000	1.8		
V_{OH}	HIGH level output voltage; all outputs	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or $V_{IL;} -I_O = 100\mu A$	2.5	2.7		2.5		V
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	2.8	3.0	717	2.8		
		V_{CC} = 4.5V; V_I = V_{IH} or V_{IL} , $-I_O$ = 100 μ A	4.3	4.5		4.3		
V	HIGH level output voltage; BUS driver	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 8\text{mA}$	2.40	2.82		2.20		V
V _{OH}	outputs	$V_{CC} = 4.5V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 16mA$	3.60	4.20		3.50]
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0				
		$V_{CC} = 2.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100\mu A$		0	0.2		0.2	1
V_{OL}	LOW level output voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} , I_O = 100 μ A		0	0.2		0.2	V
	Transfer, am carp and	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100\mu A$		0	0.2		0.2]
		$V_{CC} = 4.5V$; $V_{I} = V_{IH}$ or V_{IL} ; $I_{O} = 100\mu A$		0	0.2		0.2	
M	LOW level output voltage; BUS driver	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 8mA$		0.25	0.40		0.50	V
V_{OL}	outputs	$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 16\text{mA}$		0.35	0.55		0.65	1 °
I _I	Input leakage current	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND			1.0		1.0	μА
I _{OZ}	3-State output OFF-state current	V_{CC} = 3.6V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND			5		10	μА
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		160	μΑ
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$			500		850	μА

NOTE

^{1.} All typical values are measured at T_{amb} = 25°C.

Octal buffer/line driver (3-State)

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AC CHARACTERISTICS

GND = 0V; $t_r = t_f \le$ 2.5ns; $C_L =$ 50pF; $R_L =$ 1K Ω

			CONDITION		1	LIMITS			
SYMBOL	PARAMETER	WAVEFORM	CONDITION	_	40 to +85 °	С	-40 to -	+125 °C	UNIT
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
			1.2		50				
	Propagation delay		2.0		17	24		31	
t _{PHL} /t _{PLH}	1A _n to 1Y _n ;	Figures 1, 2	2.7		13	17		23	ns
	2A _n to 2Y _n		3.0 to 3.6		9 ²	14		18	
			4.5 to 5.5			12		15	
			1.2		65				
	3-State output enable time		2.0		22	39		49	
t _{PZH} /t _{PZL}	1 OE to 1Y _n ;	Figures 2, 3	2.7		16	29		36	ns
	2 OE to 2Y _n		3.0 to 3.6	4.3	12 ²	23		29	
			4.5 to 5.5	\$ 3°		19		24	
			1.2	30	60				
	3-State output disable time		2.0	Dr.	22	34		43	
t _{PHZ} /t _{PLZ}	1 OE to 1Y _n ;	Figures 2, 3	2.7		17	24		32	ns
	2 OE to 2Y _n		3.0 to 3.6		13 ²	21		26	
			4.5 to 5.5			16		19	

NOTES:

- Unless otherwise stated, all typical values are measured at T_{amb} = 25°C.
 Typical values are measured at V_{CC} = 3.3 V.

AC WAVEFORMS

 V_{M} = 1.5 V at $V_{CC} \geq$ 2.7 V and \leq 3.6 V

 V_{M} = 0.5 $~\times$ V_{CC} at V_{CC} < 2.7 V and \geq 4.5 V

 $\ensuremath{\text{V}_{\text{OL}}}$ and $\ensuremath{\text{V}_{\text{OH}}}$ are the typical output voltage drop that occur with the output load.

 $V_X = V_{OL} + 0.3 \ V$ at $V_{CC} \geq 2.7 \ V$ and $\leq 3.6 \ V$

 V_X = V_{OL} + 0.1 $~\times\,V_{CC}$ at V_{CC} < 2.7 V and \geq 4.5 V

 $V_Y = V_{OH} - 0.3$ V at $V_{CC} \ge 2.7$ V and ≤ 3.6 V $V_Y = V_{OH} - 0.1 \times V_{CC}$ at $V_{CC} < 2.7$ V and ≥ 4.5 V

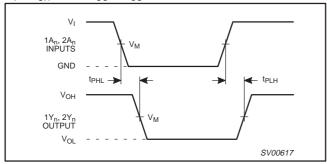


Figure 1. Input (1A_n, 2A_n) to output (1Y_n, 2Y_n) propagation delays.

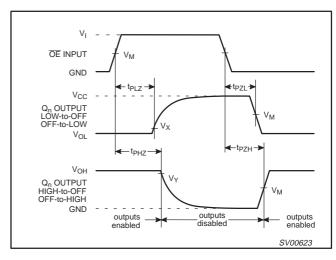


Figure 2. 3-State enable and disable times.

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TEST CIRCUIT

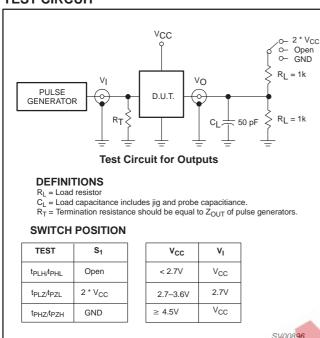


Figure 3. Load circuitry for switching times.

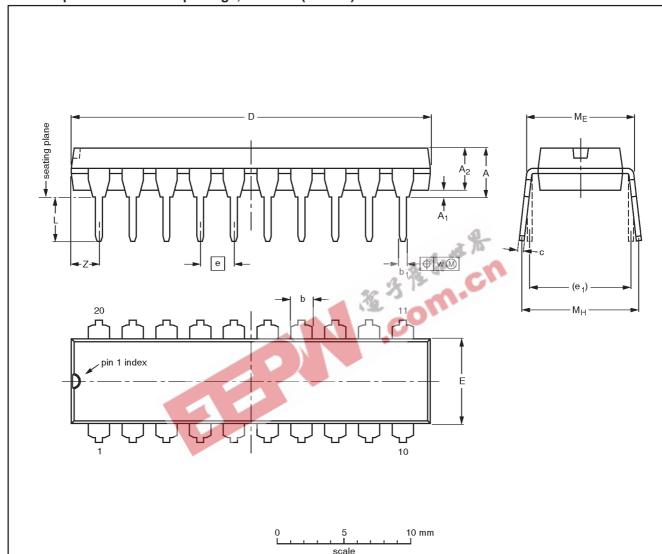


Octal buffer/line driver (3-State)

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DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

DIMENTOR	•														
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

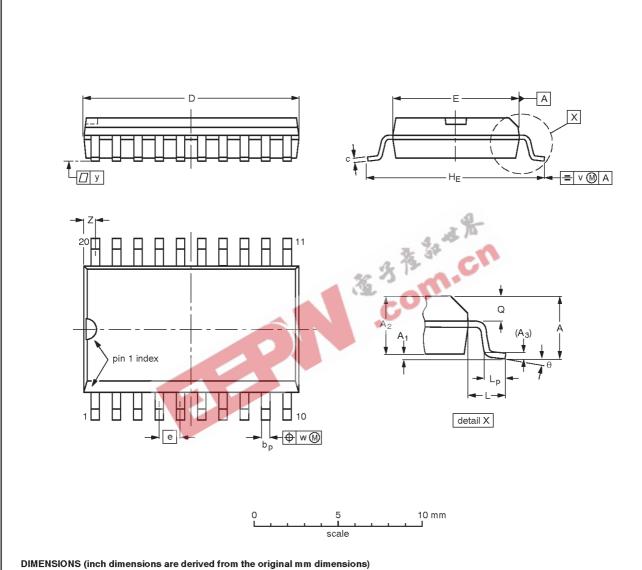
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1990E DATE	
SOT146-1			SC603		-92-11-17 95-05-24	

Octal buffer/line driver (3-State)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

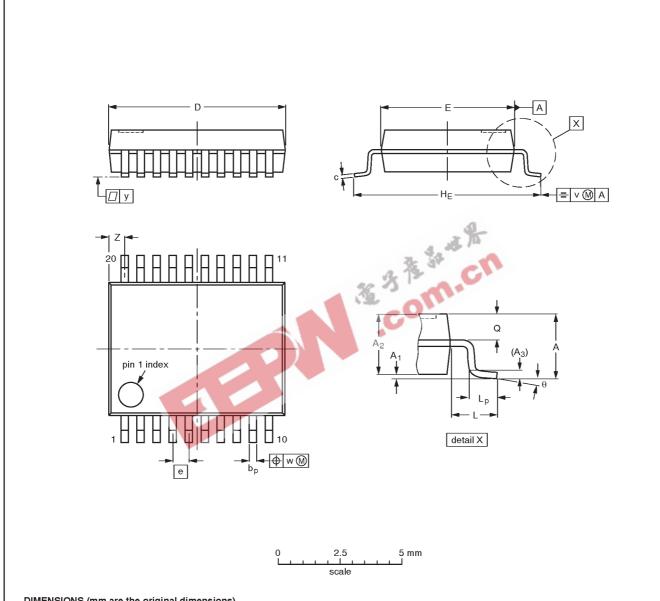
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24

Octal buffer/line driver (3-State)

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	Α3	рb	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	٦	Lp	Ø	>	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

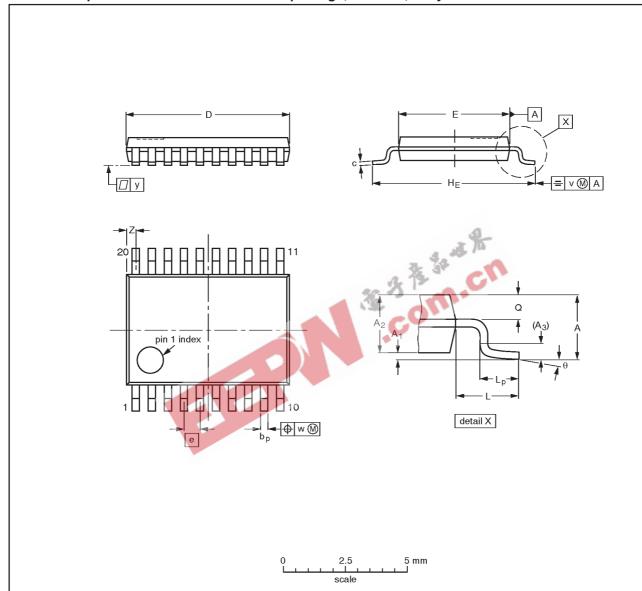
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT339-1		MO-150AE				-93-09-08 95-02-04	

Octal buffer/line driver (3-State)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE	
SOT360-1		MO-153AC				-93-06-16 95-02-04	

Octal buffer/line driver (3-State)

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Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

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